Transient Voltage Suppressors ESD Protection Diode with Low Clamping Voltage

This integrated transient voltage suppressor device (TVS) is designed for applications requiring transient overvoltage protection. It is intended for use in sensitive equipment such as computers, printers, business machines, communication systems, medical equipment, and other applications. Its integrated design provides very effective and reliable protection for four separate lines using only one package. These devices are ideal for situations where board space is at a premium. **Features**

- Low Clamping Voltage
- Small SOT-553 SMT Package
- Stand Off Voltage: 3 V
- Low Leakage Current
- Four Separate Unidirectional Configurations for Protection
- ESD Protection: IEC61000-4-2: Level 4 ESD Protection MILSTD 883C - Method 3015-6: Class 3
- Complies to USB 1.1 Low Speed & Full Speed Specifications
- These are Pb-Free Devices

Benefits

- Provides Protection for ESD Industry Standards: IEC 61000, HBM
- Protects Four Lines Against Transient Voltage Conditions
- Minimize Power Consumption of the System
- Minimize PCB Board Space

Typical Applications

- Instrumentation Equipment
- Serial and Parallel Ports
- Microprocessor Based Equipment
- Notebooks, Desktops, Servers
- Cellular and Portable Equipment

MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Value	Unit
Peak Power Dissipation (Note 1)	P _{PK}	20	W
Steady State Power – 1 Diode (Note 2)	PD	380	mW
Thermal Resistance, Junction-to-Ambient Above 25°C, Derate	R _{θJA}	327 3.05	°C/W mW/°C
Maximum Junction Temperature	T _{Jmax}	150	°C
Operating Junction and Storage Temperature Range	T _J T _{stg}	–55 to +150	°C
Lead Solder Temperature (10 seconds duration)	ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Non-repetitive current per Figure 5.
- Only 1 diode under power. For all 4 diodes under power, P_D will be 25%. Mounted on FR-4 board with min pad.

See Application Note AND8308/D for further description of survivability specs.



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SOT-553 CASE 463B PLASTIC

MARKING DIAGRAM





(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]		
NZQA5V6AXV5T1	SOT-553*	4000/Tape & Reel		
NZQA5V6AXV5T1G	SOT-553*	4000/Tape & Reel		
NZQA6V8AXV5T1	SOT-553*	4000/Tape & Reel		
NZQA6V8AXV5T1G	SOT-553*	4000/Tape & Reel		
NZQA6V8AXV5T3	SOT-553*	16000/Tape & Reel		
NZQA6V8AXV5T3G	SOT-553*	16000/Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

*This package is inherently Pb-Free.

ELECTRICAL CHARACTERISTICS

 $(T_{\Delta} = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
Ι _Τ	Test Current
ΘV_{BR}	Maximum Temperature Coefficient of V_{BR}
١ _F	Forward Current
V _F	Forward Voltage @ I _F
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}
I _{ZK}	Reverse Current
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}



*See Application Note AND8308/D for detailed explanations of datasheet parameters.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

		Breakdown Voltage V _{BR} @ 1 mA (V)		-		-	V _C Max @ I _{PP} (Note 4)		Typ Capacitance @ 0 V Bias (pF) (Note 3)		/p itance / Bias F) re 3)	vc	
Device	Device Marking	Min	Nom	Max	V _{RWM}	I _{RWM} (μΑ)	V _C (V)	I _{PP} (А)	Тур	Max	Тур	Max	Per IEC61000-4-2 (Note 5)
NZQA5V6AXV5	5P	5.3	5.6	5.9	3.0	1.0	13	1.6	13	17	7.0	11.5	Figures 1 and 2 (See Below)
NZQA6V8AXV5	6H	6.47	6.8	7.14	4.3	1.0	13	1.6	12	15	6.7	9.5	

3. Capacitance of one diode at f = 1 MHz, $V_R = 0 V$, $T_A = 25^{\circ}C$ 4. Surge current waveform per Figure 5.

5. For test procedure see Figures 3 and 4 and Application Note AND8307/D.





IEC 61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)	
1	2	7.5	4	2	
2	4	15	8	4	
3	6	22.5	12	6	
4	8	30	16	8	



Figure 3. IEC61000-4-2 Spec



Figure 4. Diagram of ESD Test Setup

The following is taken from Application Note AND8308/D – Interpretation of Datasheet Parameters for ESD Devices.

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000–4–2 waveform. Since the IEC61000–4–2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.







PACKAGE DIMENSIONS

SOT-553, 5 LEAD CASE 463B-01 **ISSUE B**



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM 2 З.

THICKNESS OF BASE MATERIAL

	м	ILLIMETE	RS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.50	0.55	0.60	0.020	0.022	0.024	
q	0.17	0.22	0.27	0.007	0.009	0.011	
c	0.08	0.13	0.18	0.003	0.005	0.007	
D	1.50	1.60	1.70	0.059	0.063	0.067	
Е	1.10	1.20	1.30	0.043	0.047	0.051	
e		0.50 BSC		0.020 BSC			
Г	0.10	0.20	0.30	0.004	0.008	0.012	
HE	1.50	1.60	1.70	0.059	0.063	0.067	

STYLE 2: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2

4. CATHODE 3 5. CATHODE 4

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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